

Revision 0.71

Absolute Maximum Ratings

SINGLE FREQUENCY LASER DIODES Distributed Bragg Reflector Laser



General Product Information	
Product	Application
633 nm DBR Laser	HeNe Laser Replacement
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Spectroscopy, Metrology, Sensing
including Monitor Diode, Thermoelectric Cooler and Thermistor	Please note: The use of the laser in
with SM Fiber with angle-polished Connector (APC)	3D trackers is protected by patents



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Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-40		85
Operational Temperature at Case	T _C	°C	-20		75
Operational Temperature at Laser Chip	T_LD	°C	-5		25
Forward Current	I _F	mA			180
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			6
TEC Current	I _{TEC}	Α			1.8
TEC Voltage	V_{TEC}	V			3.2

Measurement Conditions / Comments
Stress in excess of one of the Absolute Maximum
Ratings may damage the laser. Please note that a
damaging optical power level may occur although the
maximum current is not reached. These are stress
ratings only, and functional operation at these or any
other conditions beyond those indicated under
Recommended Operational Conditions is not implied.

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _{case}	°C	0		50
Operational Temperature at Laser Chip	T_LD	°C	10		18
Forward Current	I _F	mA		100	160
Output Power	P _{opt}	mW			5

Measurement Conditions / Comments
measured by integrated Thermistor
ex fiber

Characteristics at T _{LD}	= 15° at BOL				
Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	632	633	634
Linewidth (FWHM)	Δλ	MHz		1	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.045	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.001	
Sidemode Supression Ratio	SMSR	dB	30		

Measurement Conditions / Comments
see images on page 4
$P_{opt} = 3 \text{ mW}$





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Thermoelectric Cooler

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Characteristics at T _{LD}	= 15° at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Laser Current @ P _{opt} = 5 mW	I _{LD}	mA			160
Slope Efficiency	η	W/A	0.1	0.2	0.3
Threshold Current	I _{th}	mA		80	120
Threshold Current	lth	mA		80	120

Measurement Conditions / Comments	
Ith drift may occur, no violation of the max. value	

Symbol	Unit	min	typ	max
I _{mon} / P _{opt}	μΑ/mW	5		200
			- J	

Measi	surement Conditions / Comments	
$J_R =$	5 V	

Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		0.8	
Power Dissipation (total loss at case)	P _{loss}	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
$P_{opt} = 5 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 5 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 5 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 5 \text{ mW}, \Delta T = Tcase - TLD $

Thermistor (Standard NTC Type)					
Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	Α			1.1293 x 10	-3
Steinhart & Hart Coefficient B	В			2.3410 x 10	-4
Steinhart & Hart Coefficient C	C		3	3.7755 x 10	-8

Measurement Conditions / Com	ments
$T_{LD} = 25^{\circ} C$	
$R_1/R_2 = e^{\beta(1/T_1\cdot1/T_2)}$ at $T_{LD} =$	0° 50° C
$1/T = A + B(\ln R) + C(\ln R)^3$	
T: temperature in Kelvin	
R: resistance at T in Ohm	





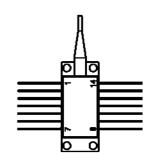
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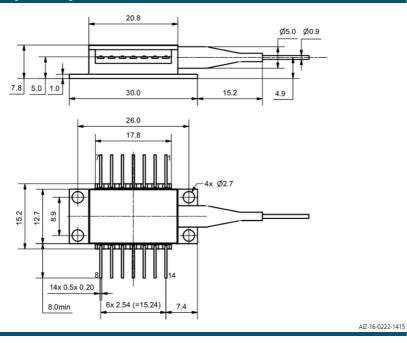


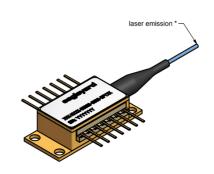
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1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected
Pins a	are isolated from case unless noted otherwise.		



Package Drawings





Fiber and Connector Type

SM Fiber	125 / 4.5 μm (l = 1 +/-0.1 m)
Connector	FC/APC (narrow key / 2mm)

Measurement Conditions / Comments





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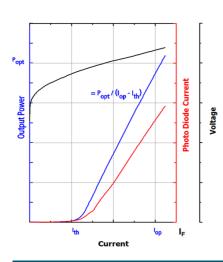
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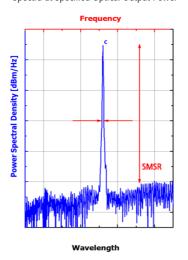


Typical Measurement Results

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DBR laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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CLASS 4 LASER PRODUCT WAVELENGTH 633 nm MAX. OUTPUT POWER 6 mV





